

Title (en)

Process of manufacturing thin "TRIP" type steel strips and strips obtained thereby

Title (de)

Verfahren zum Herstellen von dünnen "TRIP"-Typ-Stahlbändern und also hergestellte Stahlbändern

Title (fr)

Procédé de fabrication de bandes minces en acier de type "TRIP", et bandes minces ainsi obtenues

Publication

EP 1072689 B1 20040407 (FR)

Application

EP 00402035 A 20000717

Priority

FR 9910060 A 19990730

Abstract (en)

[origin: EP1072689A1] To make the TRIP (TRansformation Induced Plasticity) band, the band is continuously cast, 1.5-10 mm thick, preferably 1-5 mm thick. Composition is C 0.5-0.25, (Mn+Cu+Ni) is 0.5-3%, (Si+Al) is 0.1-4%, (P+Sn+As+Sb) is up to 0.1%, (Ti+Nb+V+Zr+rare earths) is up to 0.3%, Cr is below 1%, as are Mo, V; the balance being iron and impurities. The band is hot-laminated above the steel Ar3 temperature, with a reduction of 25-70% in one or more passes. The first forced cooling takes place at 5-100 degrees C/s. The band is held at 550-400 degrees C sufficiently long for the bainitic transformation with a proportion of residual austenite exceeding 5%, whilst avoiding perlite formation. The transformation is interrupted by a second forced cooling to 400 degrees C. The band is finally wound up, below 350 degrees C. An Independent claim is included for the band of steel so produced.

IPC 1-7

C21D 8/02

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CPC (source: EP KR US)

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Cited by

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WO2004048618A1; WO2008052921A1; WO03057928A1; US7462251B2; US7998285B2; US7354487B2; US11225697B2; US9475103B2;
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JP 2001073040 A 20010321; JP 2011047054 A 20110310; JP 4684397 B2 20110518; KR 100656974 B1 20061215;
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